Organo Group 13 metal complexes of d-block elements

VII. * Stable organogalliumtetrahydroborates: novel precursors for the deposition of gallium-containing mixed metal thin films

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Abstract

Novel, mixed substituted organogallium compounds of the type $(R^1)(R^2)Ga[(CH_2)_3NR_2]$ $(R^1, R^2 = Cl, BH_4, alkyl, (\eta^5 - C_5H_5)(CO)_2Fe; R = CH_3, C_2H_5)$ have been synthesized and fully characterized. These compounds are stabilized by intramolecular adduct formation at the gallium centre. The solid state structures of $[(\eta^5 - C_5H_5)(CO)_2]FeGa[(CH_2)_3N(CH_3)_2](R^1)$ (3a: $R^1 - C_2H_5$; 3d: $R^1 = BH_4$) exhibit Fe-Ga bond lengths of 245.65(4) pm and 237.5(1) pm respectively. The Ga-B distance in 3d amounts to 237.4(3) pm. Remarkably pure Fe/Ga thin films were grown from 3d by low pressure OMCVD. The BH₄ group reduces both the decomposition temperature of the single source precursor and the degree of contamination by carbon of the mixed metal thin films.

1. Introduction

Organometallic chemical vapour deposition (OMCVD) and metalloorganic molecular beam epitaxy (MOMBE) show great promise as superior thin film processes since they circumvent many of the problems associated with other deposition technologies [1]. However, carbon contamination is one intrinsic problem left with organometallics as precursors for pure metals and semiconductors. Another general question is, whether single source precursors are advantageous over separate sources in adjusting the stoichiometry and phase identity of multicomponent thin films [2]. In any case, it is desirable to known more about kinetically preferred decomposition pathways which can be built into the molecular structure of the precursors, for example [3]:

$$(Me_3N)AlH_2(\eta^2 H_2BH_2)(g)$$

 $\rightarrow Al(s) + 3/2H_2 + H_3BNMe_3(g)$ (1)

The key step is the migration of the amine ligand from the aluminium centre to the boron atom. Trimethylamineborane is carried away without further fragmentation and consequently Al films (free of C, N and B) were obtained. An extension of this concept to the deposition of the heavier homologues of aluminium is suggestive [3]. However, tetrahydridoborato substituted gallanes and indanes are known to decompose rapidly far below room temperature [4]. Our studies [5] on novel single source precursors for OMCVD of intermetallic materials have led us to present here our results on the synthesis, characterization and deposition properties of thermally unusually stable organogallium tetrahydridoborates and their organoiron substituted congeners.

2. Results and discussion

2.1. Synthesis and properties

The new compounds 1b-d, 2a-b, 3a-d are accessible in very high yields (> 85%) by the procedures shown in Scheme 1. The compound 1e can also be prepared by treating 1a-Et (a derivative of 1a with R = Et, see Table 1) with lithium tert-butylate (not shown in Scheme 1). 2a, b are colourless, non-pyro-

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^{**} Dedicated to Prof. Dr. Dr. h.c. mult. E.O. Fischer on the occasion of his 75th birthday.



Scheme 1.

phoric and moderately air-sensitive liquids which can be purified by short path distillation *in vacuo* at 90-100°C. This thermal stability is truly remarkable, since $[(\eta^2-H_2BH_2)Ga(CH_3)_2(NMe_3)]$, the compound most closely related to 2a, b is known to decompose rapidly

TABLE 1. Numbering scheme of the compounds of Scheme 1 $(Me = CH_3, Et = C_2H_5, {}^tBu = C(CH_3)_3, Np = CH_2C(CH_3)_3).$

	1a	1b	1c	1d	1e	2a	2b	3a	3b	3c	3d
\overline{R}^1	Cl	Et	Np	Me	^t Bu	Me	Np	Cl	Et	Np	_
R	Me	Me	Me	Et	Et	Et	Me	Me	Me	Me	Me

even at -45° C into H₃BNMe₃, H₂ and gallium metal [6]. Intramolecular adduct formation proved once again to be a good route for generation of organometallic Group 13 compounds with unusual properties [7]. Sterically demanding alkyl substituents have only a little influence on the thermal stability of those systems. Traces of gallium metal however, catalyze slow decomposition of **2a**, **b** at room temperature.

Whereas related transition metal substituted gallanes, e.g. those of Co [8] and Ni [9], are very sensitive towards moisture and oxygen, crystalline 3a-c can be handled in air. The tetrahydroborato derivative 3d is somewhat more labile and should be stored cold under nitrogen in the dark. 3a-d sublime at 60-80°C, 10^{-3} Torr.

2.2. Spectroscopic characterization

The electron impact mass spectra (70 eV) of **2a**, **b** do not show the molecular peak. However, the boroncontaining fragment $[(BH_4)Ga\{(CH_2)_3(NMe_2)\}^+]$, is clearly visible. Under the conditions of measurement, fragments like $[HB(CH_3)_2(NMe_2)^+]$ are observed, which are related to ligand migration processes similar to those mentioned in eqn. (1). The NMR spectra of



Fig. 1. Solution infrared spectra in the carbonyl region (2000-1800 cm⁻¹) obtained in CaF₂ cells (n-pentane, 25°C) for the compounds (a) **3a**, (b) **3b**, (c) **3c** and (d) **3d** (extended range: 2400-1800 cm⁻¹, including $\nu(BH_t)$ region).

the compounds 1b-e, 2a, b and 3a-d are quite similar. The chirality of these molecules causes complex 1D-¹H-NMR spectra with overlapping signal groups, which were assigned by 2D-techniques [10]. Depending on the substitution pattern, the coordination sphere around the gallium centre is more or less rigid. The ¹H-NMR spectra of **2b** at -60° C for example, show the expected sets of multiplets for the diastereotopic protons of the metallacycle, the methyl groups at the nitrogen donor atom and the methylene group of the neopentyl substituent. The ¹¹B-NMR spectra of 2b reveal a quintet centred at -34.8 ppm, which lies at the high field end of the range for η^2 -BH₄-units (free BH_4^- : -39 · · · 45 ppm) [11]. Likewise, the IR spectra of 2a reveal absorptions corresponding to a η^2 -BH₄ group at 2437, 2392 [$\nu(BH_t)$] and 2056 cm⁻¹ [$\nu(BH_b)$]. These values are very similar to those known for $[(\eta^2 H_{2}BH_{2}Ga\{(CH_{3})_{2}(NMe_{3})\}\}$ amounting to 2435, 2400 and 2080 cm^{-1} , indicating rather negatively charged BH₄-substituents [6]. The solution IR-spectra of the Fe-Ga species 3b, c show a surprising feature. While for C_1 symmetric **3a** and **3d** only the two expected ν (CO) absorptions are observed, analytically pure **3b**, c exhibit four ν (CO) bands (Fig. 1). Apparently, two conformers of 3b, c are resolved on the IR timescale at 25°C, which is not the case of the more rigid molecule 3a and the more fluxional system 3d.

2.3. Structures of 3a and 3d

The crystal structures of 3b (Fig. 2a) and 3d (Fig. 2b) have been determined. They confirm the presence of an iron-gallium bond in each compound and are consistent with the IR and NMR spectroscopic features of 3b and 3d in solution. The Fe-Ga bond lengths of 245.7 pm (3b) and 237.5 pm (3d) are comparable to those of $[(\eta^5 - C_5 H_5)(CO)_2]$ Fe-Ga $(C_5 H_4 Me)_2(C_5 H_5 N)$, 242.7 pm [12], and of {[$(\eta^{5}-C_{5}H_{5})(CO)_{2}$]Fe}₃Ga, 244.0 pm [13]. Intramolecular adduct formation to yield a five membered metallacycle completes the distorted tetrahedral coordination sphere around the gallium atoms in 3b and 3d. The Ga-N and Ga-C distances are within the range observed for related compounds [7,8]. The Ga-B distance of 237.4 pm in 3d is considerably longer than the respective value of 215.2 pm reported for $[(\eta^2-H_2BH_2)Ga(CH_3)_2]$ in the gas phase [6]. To our knowledge, 3d is the first example of a tetrahydroborato gallium compound that has been structurally characterized in the solid state.

2.4. OMCVD experiments

Low pressure OMCVD experiments using a horizontal hot-walled tube reactor were carried out according to procedures described elsewhere [5]. The Fe-Ga systems **3a** and **3c** proved to be thermally very stable.



Fig. 2. (a) A view of the molecular structure of 3b in the solid sate (ORTEP drawing, non-hydrogen atoms are shown as 50% thermal ellipsoides, hydrogen atoms are omitted for clarity). Selected bond distances (pm) and angles (degrees): Fe-Ga 245.65(4), Fe-Cl 173.0(3), Fe-C2 172.8(3), Ga-C3 200.1(3), Ga-N 218.5(2), Ga-C8 200.0(3), Fe-Cp 172.6, Cl-Fe-Ga 84.2(1), C2-Fe-Ga 78.4(1), Cl-Fe-C2 93.3(1), Fe-Ga-C3 116.8(1), Fe-Ga-N 112.3(1), C3-Ga-N 87.1(1), C3-Ga-C8 116.9(1), N-Ga-C8 105.1(1), Fe-Ga-C8 114.4(1). (b) A view of the molecular structure of 3d in the solid sate (ORTEP drawing, non-hydrogen atoms are shown as 50% thermal ellipsoides, hydrogen atoms are omitted for clarity, except H1 ··· H4 of the BH₄ substituent). Selected bond distances (pm) and angles (degrees) Fe-Ga 237.5(1), Fe-Cl 174.2(4), Fe-C2 174.3(3), Ga-C3 199.1(4), Ga-N 218.5(3), Ga-B 237.4(3), Fe-Cp 171.9, Cl-Fe-Ga 90.8(1), C2-Fe-Ga 82.6(1), Cl-Fe-C2 96.5(2), Fe-Ga-C3 131.2(1), Fe-Ga-N 118.2(1), C3-Ga-N 87.3(1), C3-Ga-B 103.5(2), N-Ga-B 103.0(1), Fe-Ga-B 109.2(1), H1-B-H2 102.4.

Fe/Ga films could only be obtained above 500°C and were heavily contaminated with carbon. The ethyl derivative **3b** gave some deposition at 350°C, while most (> 90%) of the precursor compound still passed the hot zone (1 = 10 cm, $\emptyset = 2.5$ cm) unchanged and collected in the cold trap behind. The tetrahydroborato complex **3d** instead was quantitatively pyrolyzed into Fe/Ga deposits and gaseous by-products between 250 and 350°C (10⁻² Torr). The characterization of the

Fig. 3. AUGER spectrum (Perkin-Elmer Phi 595, 3 kV, $0.2 \ \mu A$ primary beam intensity) of an Fe/Ga thin film after removing surface contaminations with argon ion sputtering (2 min). Approximate composition of the thin film as calculated from the signal intensities using standard sensitivity factors [14]: Fe, 48(1); Ga, 38(1); C, 3(1), O 4(1), atom%; (N not detectable). The low contaminations of B and presumably Cl (trace impurities in the precursor compound **3d**) are difficult to quantisize due to their overlapping KLL bands.

obtained mixed metal thin films is still in progress. A typical AUGER spectrum of a roughly 4000 Å thick Fe/Ga film grown at 350°C (10^{-2} Torr) on a quartz slide is given in Fig. 3. Alkylboranes, *e.g.* H₂B-[(CH₂)₃N(CH₃)₂], were detected in the effluent.

3. Conclusions

Intramolecular adduct formation at the gallium centre stabilizes organogallium tetrahydroborates and their organoiron substituted congeners to render these compounds potential precursors for the deposition of gallium-containing thin films. Remarkably pure Fe/Ga films could be grown from **3d** by low pressure OM-CVD. The introduction of the BH₄ substituent at the gallium centre significantly reduces both the decomposition temperature of the single source precursor and the carbon contamination of the Fe/Ga thin films. This results show that the concept depicted in eqn. (1) might indeed be extendable to even more complex deposition problems.

4. Experimental section

All manipulations were undertaken with standard Schlenk and glove box techniques under inert gas atmosphere (purified N₂) using carefully dried (<2 ppm H₂O) oxygen-free solvents. All samples for NMR spectra were contained in vacuum sealed NMR tubes. ¹H and ¹³C NMR spectra were referenced to internal solvent and corrected to TMS. ¹¹B NMR spectra were referenced to external 10% H_3BO_3/H_2O set at -18.2 ppm. The m/z values are reported for ¹¹B, ³⁵Cl, ⁶⁹Ga and ⁵⁶Fe, normal isotope distribution observed. For further information concerning experimental and analytical techniques see Refs. [8,9].

4.1. Syntheses

4.1.1. Chloro[3-(dimethylamino)propyl]ethylgallium (1b), chloro[3-(dimethylamino)propyl]neopentylgallium (1c) and chloro[3-(diethylamino)propyl]metylgallium (1d)

A two necked round bottom flask (250 ml) was charged with 7.2 g (42.2 mmol) freshly sublimed EtGaCl₂ [15], which was dissolved in 50 ml Et₂O at -78° C. A suspension of 3.9 g (42.4 mmol) Li[(CH₂)₃NMe₂] [16] in 70 ml Et₂O was then slowly added with stirring. The mixture was allowed to warm to r.t. during 1 h and stirred for an additional 5 h. After filtration and vacuum distillation of the solvent at r.t., the pure product, 8.7 g (94%), was obtained by short path distillation at 82–86°C (10⁻³ Torr, dyn. vac.). 1c and 1d were prepared analogously. Typical yields: > 90%.

1b: colourless liquid, bp. 82°C, 10^{-3} Torr. ¹H NMR (399.78 MHz, d_8 -toluene, 25°C): δ 0.52 (m, 5H, Ga-CH₂CH₂ and GaCH₂CH₃), 1.21 (t, 2H, ³J(H, H) = 8.0 Hz, GaCH₂CH₃), 1.26 and 1.55 (br, 2H, GaCH₂CH₂), 1.65 and 2.11 (s, br, 6H, NCH₃), 1.70 and 2.15 (br, 2H, CH₂N). ¹³C NMR (100.5 MHz, d_8 -toluene, 25°C): δ 5.4 (t, GaCH₂CH₃), 8.5 (t, GaCH₂CH₂), 10.0 (q, Ga-CH₂CH₃), 22.6 (t, GaCH₂CH₂), 45.5 and 46.7 (q, br, NCH₃), 62.7 (t, CH₂N). IR (neat, NaCl; selected values [cm⁻¹]): ν (C-H) 3002m, 2919vs, 2865vs, 2813m; δ(C-H) 1466vs, 1436m, 1418m, 1323m, 1281m; others: 1035s, 977s, 907s, 772s, 697s, 645s. Anal. calc. for C₇H₁₇CIGaN (found) C, 38.15 (37.90); H, 7.77 (7.74); N, 6.36 (6.57); Cl, 16.09 (16.05); Ga, 31.63 (31.10)%.

1c: white solid, mp. 36°C. ¹H NMR (399.78 MHz, d_8 -toluene, 25°C): δ 0.65 and 0.95 (d, ¹J(H, H) = 13.2 Hz; 2H, GaCH₂CMe₃), 0.75 (br, 2H, GaCH₂CH₂), 1.25 and 1.55 (br, 2H, GaCH₂CH₂), 1.50 and 2.06 (s, 6H, NCH₃), 1.61 and 2.15 (br, 2H, CH₂N). ¹³C NMR (100.5 MHz, d_8 -toluene, 25°C): δ 11.3 (t, GaCH₂CH₂), 22.7 (t, GaCH₂CH₂), 31.2 (t, GaCH₂CMe₃), 33.3 (s, CH₂CMe₃), 34.0 (q, C(CH₃)₃), 43.9 and 46.6 (q, NCH₃), 62.4 (q, CH₂N). IR (nujol mull, NaCl; selected values, [cm⁻¹]): δ(C–H) 1464vs, 1420m, 1412m, 1381 m, 1362m; other 1036s, 1025s, 981s, 905s, 865m, 773s, 720s, 692s, 628s. Anal. calc. for C₁₀H₂₃ClGaN (found): C, 45.76 (45.78); H, 8.83 (8.63); N, 5.34 (5.32); Cl, 13.51 (13.39); Ga, 26.56 (25.80)%. 1d: white solid, mp. 34°C. ¹H NMR (60 MHz, C_6D_6 , 25°C) $\delta - 0.1$ (s, 3H, GaCH₃), 0.70 (t, 6H, $-CH_2CH_3$) 0.50 (t, 2H, GaCH₂), 1.20–1.70 (m, br, 2H, GaCH₂CH₂), 2.03–2.56 (m, 6H, NCH₂). Anal. calc. for $C_8H_{19}NClGa$ (found): C, 40.99 (40.76); H, 8.17 (8.15); N 5.98 (5.87)%.

4.1.2. Chloro[3-(diethylamino)propyl](tert-butyl)gallium (1e)

Tert-butyllithium (540 mg; 8.43 mmol) dissolved in toluene (20 ml) was added dropwise to a solution of 2.16 g (8.48 mmol) **1a**-Et (derivative of **1a**: $\mathbf{R} = \text{Et}$, see Table 1) in 50 ml toluene at -78° C. The reaction mixture was allowed to warm to r.t. during 1 h and was stirred for an additional 3 h. Work up according to the procedure above gave 1.92 g (82%) **1e**.

1e: colourless liquid, bp. 73-78°C, 10^{-3} Torr. ¹H NMR (399.78 MHz, d_8 -toluene, 25°C) δ 0.42 and 0.80 (t, 6H, -CH₂CH₃) 0.44-0.63 (AA'BB', 2H, GaCH₂), 1.13 (s, 9H, C(CH₃)), 1.18-1.63 (AA'BB'CC', 2H, $GaCH_2CH_2$), 1.99–2.05 (AA'BB', 2H, CH_2CH_2N), 2.04-2.16, 2.19-2.21, 2.36-2.52 and 2.76-2.92 (ABX₃, 4H, NC H_2 CH₃). ¹³C NMR (100.5 MHz, d_8 -toluene, 25°C) δ 5.5 and 10.8 (q, NCH₂CH₃), 5.7 (t, GaCH₂), 21.8 (t, $GaCH_2CH_2$), 23.7 (s, CMe_3), 30.3 (q, $C(CH_3)_3$, 41.6 and 46.2 (t, NCH₂CH₃), 56.4 (t, CH₂CH₂N). IR (neat): ν (CH) 2981m, 2950s, 2919s, 2872m, 2841s; δ (CH) 1469s, 1387m, 1359m; others: 1037m, 1014m, 952m, 811m, 732m, 688w. EI-MS (20°C, 70 eV): m/z (%) = [M⁺] 275 (n. obs.), [M⁺-Cl] 240 (23), $[M^+ - C_4 H_0]$ 218 (100), $[M^+ - Cl - C_4 H_0]$ 183 $(3), [(C_2H_5)_2NCH_2CHCH_2] 113 (23), [(C_2H_5)_2NCH_2^+]$ 86 (88), $[C_4H_9^+]$ 57 (25). Anal. calc. for $C_{11}H_{25}NClGa$ (found): C, 46.79 (46.78); H, 9.04 (9.11); N, 4.74 (5.07)%.

4.1.3. [3-(diethylamino)propyl]methyl(η^2 -tetrahydroborato)gallium (2a) and [3-(dimethylamino)propyl]neopentyl(η^2 -tetrahydroborato)gallium (2b)

To a solution of 1.42 g (6.1 mmol) 1d in Et₂O 128 mg (6.1 mmol) of solid Li[BH₄] was added at -10° C. The mixture was stirred at this temperature for a period of 12 h. The deposited LiCl was removed by filtration (230 mg; 89%). The obtained solution was then concentrated at room temperature *in vacuo*. The product was finally purified by short path distillation at 85–88°C (10^{-3} Torr, dyn. vac.). Pure 2a was obtained as a colourless, non-pyrophoric, air-sensitive liquid (1.10 g, 85%). 2b was prepared analogously from 2.50 g (9.5 mmol) 1c and 210 mg (10 mmol) Li[BH₄]. Yield: 2.13 g (93%).

2a: ¹H NMR (60 MHz, C_6D_6 , 25°C) δ -0.1 (s, 5H, GaCH₂ and GaCH₃), 0.70 (t, 6H, $-CH_2CH_3$), 1.50 (quint. br, 2H, GaCH₂CH₂), 1.93-2.63 (m, 6H, NCH₂). ¹³C NMR (100.5 MHz, d_8 -toluene, -50° C): δ 6.03 (q.

GaCH₃), 7.9 and 9.6 (q, NCH₂CH₃), 8.6 (t, GaCH₂), 21.9 (t, GaCH₂CH₂). 41.4 and 46.2 (q, NCH₃), 55.6 (q, CH₂N). ¹¹B NMR (128.3 MHz, C₆D₆, 25°C): δ – 35.4 (quint, ¹J(¹¹B, H) 82 Hz). IR (nujol mull, NaCl; selected values, [cm⁻¹]): ν (B-H) 2437s, 2392s, 2056m. Anal. calc. for C₈H₂₃BGaN (found): C, 44.94 (44.78); H, 10.84 (11.05); N, 6.55 (6.35)%.

2b: colourless liquid, bp. 96°C (10^{-3} Torr). ¹H NMR (399.78 MHz, d_8 -toluene, -60° C): δ 0.45 and 0.85 (d, ${}^{1}J(H, H) = 13.4 Hz; 2H, GaCH_{2}CMe_{3}), 0.65$ (br, 2H, $GaCH_2CH_2$), 1.22 and 1.65 (br, 2H, $GaCH_2CH_2$), 1.78 and 1.99 (s, 6H, NCH₃), 1.85 and 2.20 (br, 2H, CH₂N). ¹³C NMR (100.5 MHz, d_8 -toluene, -60° C): δ 11.4 (t, GaCH₂CH₂), 22.7 (t, GaCH₂CH₂), 31.4 (t, $GaCH_2CMe_3$), 32.3 (s, CH_2CMe_3), 33.8 (q, $C(CH_3)_3$), 44.4 and 46.8 (q, NCH₃), 62.6 (q, CH₂N). ¹¹B NMR (128.3 MHz, $C_6 D_6$, 25°C): δ -34.8 (quint, ¹J(¹¹B, H) 82 Hz). IR (nujol mull, NaCl; selected values, $[cm^{-1}]$): v(B-H) 2439s, 2395s, 2058m. EI-MS (25°C, 70 eV) m/z (%) = [M⁺] 241 (n. obs.). [M⁺-{CH₂CMe₃}] 170 (20), $[HGa{(CH_2)_3NMe_2}^+]$ 156 (100), $[HB{(CH_2)_3N-1}]$ Me_2 ⁺] 98 (10). Anal. calc. for $C_{10}H_{27}BGaN$ (found): C, 49.66 (49.38); H, 11.25 (11.15); N, 5.79 (5.65)%.

4.1.4. Chloro[η^5 -cyclopentadienyl)(dicarbonyl)iron]-[3-(dimethylamino)propyl]gallium (3a), [η^5 -cyclopentadienyl)(dicarbonyl)iron]ethyl[3(dimethylamino)propyl]gallium (3b) and [η^5 -cyclopentadienyl)(dicarbonyl)iron][3-(dimethylamino)propyl]neopentylgallium (3c)

A solution of 7.4 mmol $K[(\eta^5-C_5H_5)(CO)_2Fe]$ in 50 ml THF was prepared by reduction of 1.30 g (3.7 mmol) $[(\eta^5 - C_5 H_5)(CO)_2 Fe]_2$ with 1.00 g (7.4 mmol) potassium graphite (C_8K) according to a procedure published elsewhere [9]. This solution was then cooled to -78°C. 1.70 g (7.5 mmol) 1a, dissolved in 20 ml THF, was then quickly added with vigorous stirring. The stirred reaction mixture was then allowed to warm to r.t. within 1 h. After filtration and removing the solvent in vacuo, the off-white residue obtained was washed three times with 25 ml n-pentane at 0°C. The crude product was further purified by recrystallization from concentrated toluene solutions layered with nheptane at 25°C to -78°C; yield: 2.4 g (88%). 3b and 3c were each prepared analogously from 0.80 g (2.3 mmol) $[(\eta^{5}-C_{5}H_{5})(CO)_{2}Fe]_{2}$ and 0.62 g (4.5 mmol) C₈K with 1.00 g (4.5 mmol) 1b and 1.20 g (4.5 mmol) 1c respectively. However, due to the good solubility of 3b, c in hydrocarbons the products were extracted (rather than washed) with *n*-pentane. Crystallization at -78° C from the combined, concentrated and filtered extracts gave 1.34 g (82%) **3b** and 1.56 g (86%) **3c** respectively.

3a: nearly colourless crystals, mp. 72°C, subl. 60°C 10^{-3} Torr; ¹H NMR (399.78 MHz, d_8 -toluene, 25°C): δ

0.85 and 0.98 (AA'BB', 2H, GaCH₂), 1.47 (AA'BB'CC', 1H, GaCH₂CH₂), 1.68–1.80 (m, 2H; AA'BB'CC, GaCH₂CH₂ and AA'BB', CH₂N), 1.90 and 2.36 (s, 6H, NCH₃), 2.44 (m, 1H, AA'BB', CH₂N), 4.32 (s, C₅H₅). ¹³C NMR (100.5 MHz, d₈-toluene, 25°C): δ 18.2 (t, GaCH₂), 22.9 (t, GaCH₂CH₂), 43.9 and 47.2 (q, NCH₃), 62.2 (s, CH₂N), 82.5 (d, C₅H₅; with ¹H-decoupling below – 50°C; four out of five diastereotopic C_{ring} atoms are resolved), 217.8 and 217.4 (s, FeCO). IR (*n*-pentane, cm⁻¹): ν (CO) = 1977vs, 1924vs. EI-MS (35°C, 70 eV) *m/z* (%) = [M⁺] 367 (1), [M⁺ - Cl] 332 (25). Anal. calc. for C₁₂H₁₇ClFeGaNO₂ (found): C, 39.14 (39.15); H, 4.70 (4.65); N 3.75 (3.80)%.

3b: slightly reddish crystals, mp. 66°C, subl. 60°C 10^{-3} Torr; ¹H NMR (399.78 MHz, d_8 -toluene, -30° C): δ 0.59 (t, ³*J*(H, H) = 8.0 Hz; 2H, GaCH₂CH₃), 0.74 and 0.84 (AA'BB', 2H, GaCH₂CH₂), 1.62 and 1.74 (AA'BB'CC', 2H, GaCH₂CH₂), 1.78 and 1.91 (s, 6H, NCH₃), 1.80 and 2.05 (AA'BB', 2 H, CH₂N), 4.17 (s, C₅H₅). ¹³C NMR (100.5 MHz, d_8 -toluene -30° C): δ 12.0 (q, GaCH₂CH₃), 13.0 (t, GaCH₂), 13.6 (t, GaCH₂), 24.5 (t, GaCH₂CH₂), 46.5 and 47.1 (q, NCH₃), 64.1 (t, CH₂N), 81.1 (d, C₅H₅), 219.5 and 219.8, (s, FeCO). IR (n-pentane, cm⁻¹): ν (CO) = 1968s, 1960vs, 1911s; 1904vs. EI-MS (25°C, 70 eV) m/z (%) = [M⁺] 361 (1), [M⁺-{ η^5 -C₅H₅Fe(CO)₂]] 184 (100). Anal. calc. for C₁₄H₂₂FeGaNO₂ (found): C, 46.46 (46.54); H, 6.13 (6.22); N 3.87 (3.73)%.

3c: colourless crystals, mp. 72°C, subl. 60°C 10⁻³ Torr; ¹H NMR (399.78 MHz, d_8 -toluene, -30° C): δ 0.82 and 0.91 (d, ¹J(H, H) = 13.4 Hz; 2H, $GaCH_2CMe_3$), 0.93 and 1.02 (AA'BB', 2H, $GaCH_2CH_2$), 1.58 and 1.81 (AA'BB'CC', 2H, GaCH₂CH₂), 1.74 and 1.91 (s, 6H, NCH₃), 1.81 and 2.30 (AA'BB', 2H, CH₂N), 4.17 (s, C₅H₅). ¹³C NMR (100.5 MHz, d_8 -toluene, -30° C): δ 17.7 (q, GaCH₂CH₂), 24.3 (t, GaCH₂CH₂), 32.1 (s, CMe₃), 34.1 (q, $C(CH_3)_3$), 39.7 (t, $GaCH_2CMe_3$), 46.7 and 48.1 (q, NCH₃), 63.6 (t, CH₂N), 81.4 (d, C_5H_5), 219.6 and 220.3 (s, FeCO). IR (n-pentane, cm⁻¹): ν (CO) = 1967s, 1956vs, 1910s, 1900vs. EI-MS (25°C, 70 eV): $m/z(\%) = [M^+]$ 403 (n. obs.), $[M^+ - \{CH_2C(CH_3)_2\}]$ 332 (5), $[M^+ - \{CH_2C(CH_3)_3\}] - 2$ CO] 276 (2), $[M^+$ $-\{\eta^{5}-C_{5}H_{5}Fe(CO)_{2}\}$] 226 (100). Anal. calc. for $C_{17}H_{28}FeGaNO_2$ (found): C, 50.54 (50.39); H, 6.99 (6.88); N, 3.47 (3.34); Fe, 13.82 (14.66); Ga 17.26 (16.70)%.

4.1.5. $[\eta^5$ -Cyclopentadienyl)(dicarbonyl)iron][3-(dimethylamino)propyl](η^2 -tetrahydroborato)gallium (**3d**)

4.10 g (11.1 mmol) **3a** was dissolved in 50 ml Et_2O at 0°C. A solution of 265 mg (12.2 mmol) Li[BH₄] dissolved in 20 ml Et_2O was then added in one portion.

While stirring the mixture at 0°C for 2 h, a white precipitate separated. The slightly yellow-orange coloured solution was filtered and all volatile constituents were removed *in vacuo*. The oily orange-brown residue was dissolved in a minimum amount of toluene (5 ml). This solution was filtered again and carefully layered with 20 ml n-heptane. Slow cooling from 0°C to -50°C afforded 2.82 g (73%) **3d** as well-shaped yellow-orange prisms.

3d: yellow-orange crystals, mp. 63°C, subl. 60° C 10^{-3} Torr; ¹H NMR (399.78 MHz, d_8 -toluene, -60° C): δ 0.95 and 1.25 (AA'BB', 2H, GaCH₂CH₂), 1.33 and 1.57 (AA'BB'CC', 2H, GaCH₂CH₂), 1.65 and 1.93 (s. 6H, NCH₃), 1.68 and 1.95 (AA'BB', 2H, CH₂N and NCH₃), 4.15 (s, C₅H₅). ¹³C NMR (100.5 \overline{MHz} , d_{g} toluene, -50° C): δ 18.0 (t, GaCH₂CH₂), 23.0 (t, GaCH₂CH₂), 45.2 and 47.4 (q, NCH₃), 62.5 (t, CH₂N), 82.2 (d, C_5H_5 ; with ¹H decoupling: three out of five diastereotopic C_{ring} atoms could be resolved), 217.2 and 216.5, (s, FeCO). ¹¹B NMR (128.3 MHz, d_8 toluene, 25°C): $\delta - 31.3$ (quint., ${}^{1}J({}^{11}B-H) = 85$ Hz); IR (toluene, cm⁻¹): ν (CO) = 1975vs, 1920vs; ν (B-H_t) = 2419 m, 2376 m. EI-MS (25°C, 70 eV) m/z(%) = 347 $[M^+]$ (n. obs.), 332 $[M^+ - (BH_3)]$ (2), 156 $[HGa(CH_2)_3]$ $N(CH_3)_2^+$] (42), 58 $[CH_2N(CH_3)_2^+]$ (100). Anal. calc. for C₁₂H₂₁BFeGaNO₂ (found): C, 41.46 (40.94); H, 6.09 (5.44); N 4.03 (3.14)%.

4.2. Single crystal structure determination of 3b and 3d

X-ray structure of **3b**: a = 785.2(3), b = 1494.7(2), c = 1349.2(4) pm, $\beta = 91.45(2)^{\circ}$, $V = 1583 \cdot 10^{6}$ pm³, data collection at 23°C, $\rho_{calc} = 1.519 \text{ gcm}^{-3}$, $\mu = 26.1$ cm⁻¹, $F_{(000)} = 744$, Z = 4, monoclinic crystal system, space group $P 2_1/n$ (No. 14), Enraf-Nonius CAD4. $\lambda = 71.07 \text{ pm} (\text{Mo}_{K\alpha}, \text{ graphite monochromator}), \text{ range}$ of measurement $1.0^{\circ} < \Theta < 25^{\circ}$, ω -scan, scan width (1.3 $+0.3 \tan \Theta$)° ($\pm 25\%$ before and after each reflection to determine the background), $t_{max} = 90$ s. 3114 measured reflections (h, k, ± 1), 2560 independent reflections of which 2363 had $I > 2 \cdot \sigma(I)$, structure determination with Patterson methods and difference Fourier syntheses, empirical absorption correction based on Ψ -scan data, transmission coefficients 0.789–0.997, 260 least squares parameters, all 19 heavy atoms with anisotropic thermal parameters, all 22 hydrogen atoms found and independently refined (isotropic), anomalous dispersions [17] accounted for, shift/error < 0.0001, R = $\Sigma(||F_o| - |F_c||)/\Sigma|F_o| = 0.0287$, $R_w = [\Sigma w(|F_o| - |F_c|)^2/\Sigma w|F_o|^2]^{1/2} = 0.032$, residual electron density +0.86 $\Delta e A^{-3}$ (100 pm besides Fe)/-0.31 $\Delta e \AA^{-3}$, weighting scheme of Tukey and Prince [18] with three refined parameters P(1) = 1.62, P(2) =0.222, P(3) = 1.30.

X-ray structure of 3d: a = 834.7(1), b = 1157.2(1), c = 1614.0(1) pm, $\beta = 102.15(1)^{\circ}$, $V = 1524 \cdot 10^{6}$ pm³, data collection at -80° C, $\rho_{calc} = 1.522$ g cm⁻³, $\mu = 97.7$ cm^{-1} , $F_{(000)} = 712$, Z = 4, monoclinic crystal system, space group $P2_1/n$ (No. 14), Enraf-Nonius CAD4, $\lambda = 154.18 \text{ pm} (\text{Cu}_{K\alpha})$, range of measurement $1.0^{\circ} < \Theta$ $< 70^{\circ}, \omega/2\Theta$ -scan, scan width $(1.0 + 0.25 \tan \Theta)^{\circ}$ ($\pm 25\%$), t_{max} = 90s, 5896 measured reflections (\pm h, k, \pm 1), 2797 independent reflections of which 2343 had $I > 3.4 \cdot \sigma(I)$, structure determination with Patterson methods and difference Fourier syntheses, empirical absorption correction based on Ψ -scan data, transmission coefficients 0.434-1.0, 207 least squares parameters, all 18 heavy atoms with anisotropic thermal parameters. Hydrogen atoms: from a total of 21 hydrogen atoms 11 hydrogen atoms bonded to carbon atoms were found by difference Fourier techniques and independently refined (isotropic), 6 hydrogen atoms bonded to carbon atoms were placed in ideal geometry and included in structure factors calculations but not refined. H1 and H2 of the BH_4 group were found, H3 and H4 were placed in ideal geometry and the whole BH_4 unit was then included in the structure factor calculations as riding group. Anomalous dispersions [17] accounted for, shift/error < 0.0001, R = $\sum (||F_{o}| - |F_{c}||) / \sum |F_{o}| = 0.0397, R_{w} = [\sum w(|F_{o}| - |F_{c}|)^{2} / \sum w |F_{o}|^{2}]^{1/2} = 0.0449, \text{ residual}$ electron density +0.76 $\Delta e A^{-3}$ (129 pm beside C6)/-0.40 $\Delta e Å^{-3}$, weighting scheme of Tukey and Prince [18] with three refined parameters P(1) = 3.85, P(2) =0.0352, P(3) = 3.17.

All calculations were performed on a DECstation 5000/25 using the programs CRYSTALS [19] and PLATON [20]. Further information on the crystal structure determinations can be obtained from the Fachinformation-szentrum Karlsruhe, Gesellschaft für wissenschaftlich technische Information mbH, W-76344 Eggenstein-Leopoldshafen, under the depository number CSD-57617, the names of the authors and the journal citation.

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